PATENT

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

METHOD OF FABRICATING A SEMICONDUCTOR DEVICE COMPRISING A GATE DIELECTRIC MADE OF HIGH DIELECTRIC PERMITTIVITY MATERIAL

tne spe	ecification of which:	(check one)					
XXX	is attached hereto) .					
	as Application Se	Docket Number rial No					
	and was amende	d on	(if applica	able).			
		reviewed and unde mended by any ame			identified spe	ecification,	
	wledge the duty to ance with 37 CFR	disclose information 1.56.	n which is materia	l to the patentab	oility of this app	olication in	
invento	r's certificate listed	of foreign priority un d below and have a ng a filing date befor	lso identified belo	ow any foreign a	application for	patent or	
Prior Foreign Application(s):					Priority Cla	imed	
03 040 (Numb		FRANCE (Country)	April 1, 20 (Filing Da		_X_Yes _	No	
I hereby claim the benefit of United States priority under 35 USC 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in a listed prior United States application in the manner provided by the first paragraph of 35 USC 112, I acknowledge the duty to disclose information material to the patentability of this application as defined in 37 CFR 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:							
(Applica	ation Serial #)	(Filing Date	te)	(Status))		
l hereb	y declare that all st	atements made her	ein of my own kno	owledge are true	and that all s	tatements	

Docket No. 03-GR1-020

application or any patent issued thereon.

made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 USC 1001 and that such willful false statements may jeopardize the validity of the

EXPRESS MAIL LABEL NO. EV381146341US

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorneys and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

Lisa K. Jorgenson	Reg. No. 34,845	Jon A. Gibbons	Reg. No. 37,333
Mario Donato	Reg. No. 37,816	Jose Gutman	Reg. No. 35,171
Nainesh Shah	Reg. No. 40,166	Stephen Bongini	Reg. No. 40,917
Martin Fleit	Reg. No. 16,900	Jeffrey Giunta	Reg. No. 42,583
Robert C. Kain	Reg. No. 30,648	Paul Bianco	Reg. No. 43,500

Direct all telephone calls to Jon A. Gibbons (561) 989-9811 and all correspondence to Customer Number 23334.

23334.	
FULL NAME OF INVENTOR: Vincent COSNIER	
INVENTOR'S SIGNATURE:	DATE:
RESIDENCE: 7, rue Henri Le Chatelier, 38000 Grenoble, France	
CITIZENSHIP: France	
POST OFFICE ADDRESS: Same as above	
FULL NAME OF INVENTOR: Yves MORAND	
INVENTOR'S SIGNATURE:	_DATE:
RESIDENCE: 16, rue A. Morel, 38000 Grenoble, France	
CITIZENSHIP: France	
POST OFFICE ADDRESS: Same as above	
FULL NAME OF INVENTOR: Olivier KERMARREC	
INVENTOR'S SIGNATURE:	_DATE:
RESIDENCE: 3, allée des Iris, 38610 Gieres, France	~
CITIZENSHIP: France	
POST OFFICE ADDRESS: Same as above	
FULL NAME OF INVENTOR: Daniel BENSAHEL	
NVENTOR'S SIGNATURE:	_DATE:
RESIDENCE: 49, rue Louise Michel, 38100 Grenoble, France	
CITIZENSHIP: France	
POST OFFICE ADDRESS: Same as above	
FULL NAME OF INVENTOR: Yves CAMPIDELLI	
NVENTOR'S SIGNATURE:	_DATE:
RESIDENCE: 1, place Hubert Dubedout, 38000 Grenoble, France	
CITIZENSHIP: France	

POST OFFICE ADDRESS: Same as above